

Development of density functional theory for plasmon assisted superconductors

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Poster 28 (arXiv:1303.5052, 1305.0390)

Poster 29 (arXiv:1303.5138) SCDFT study on Alkali-doped fullerides



Yusuke Nomura (Univ. Tokyo)

Poster 26 (arXiv:1305.2995) Ab initio downfolding method for electron-phonon coupled systems & Application to iron-based superconductors







DFT for superconductors (SCDFT) Gro

Lecture by Prof. Profeta Gross et al., 1988, 2001, 2005

- Formalism free from empirical parameters (such as μ* in the Migdal-Eliashberg theory)
- T_c reproduced successfully for conventional superconductors (such as simple metals, MgB₂, CaC₆...)
- Development of SCDFT for unconventional SC
 - Plasmon mechanism
 - Application to Li under high pressure (T_c >10K)





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DFT for normal state

$$\hat{H_e} = T_e + W_{ee} + \int \hat{\rho} v(r) \mathrm{d}^3 r$$

Hohenberg-Kohn theorem



one-to-one correspondence

Kohn-Sham equation

$$\left(-\frac{\nabla^2}{2} + v_s(r) - \mu\right)\phi_i(r) = E_i\phi_i(r) \qquad \rho\left(r\right) = \sum_j \left|\phi_j\left(r\right)\right|^2$$
$$v_s[\rho] = v_{ext} + v_H^{ee}[\rho] + v_{xc}[\rho] \qquad v_{xc} = \frac{\delta E_{xc}}{\delta\rho}$$

(Nuclei are treated by the Born-Oppenheimer approx.)



DFT for superconductors

Oliveira et al., PRL 60, 2430 (1988)M. Lüders et al, PRB <u>72</u>, 024545 (2005)Kreibich & Gross PRL 86, 2984 (2001)M. Marques et al, PRB <u>72</u>, 024546 (2005)

$$\hat{H}_{e}^{\hat{}} = T_{e} + W_{ee} + \int \hat{\rho} \hat{v}(r) d^{3}r - \int d^{3}r \int d^{3}r' \left(\chi(r, r') \Delta^{*}(r, r') + \text{H.c.} \right)$$

$$\rho\left(r\right) = \left\langle \sum_{\sigma=\uparrow\downarrow} \hat{\psi}_{\sigma}^{+}\left(r\right) \psi_{\sigma}\left(r\right) \right\rangle \quad \text{electron density}$$

$$\chi(r, r') = \left\langle \hat{\psi}_{\uparrow}^{-}\left(r\right) \psi_{\downarrow}\left(r'\right) \right\rangle \quad \text{anomalous density}$$

Hohenberg-Kohn theorem for superconductors

$$[v,\Delta] \longleftrightarrow [\rho,\chi]$$





Kohn-Sham BdG equation

Oliveira et al., PRL 60, 2430 (1988)M. Lüders et al, PRB <u>72</u>, 024545 (2005)Kreibich & Gross PRL 86, 2984 (2001)M. Marques et al, PRB <u>72</u>, 024546 (2005)

$$\left(-\frac{\nabla^2}{2} + \mathbf{v}_s(\mathbf{r}) - \mu\right) u_i(\mathbf{r}) + \int d^3 \mathbf{r}' \Delta_s(\mathbf{r}, \mathbf{r}') v_i(\mathbf{r}') = E_i u_i(\mathbf{r})$$
$$-\left(-\frac{\nabla^2}{2} + \mathbf{v}_s(\mathbf{r}) - \mu\right) v_i(\mathbf{r}) + \int d^3 \mathbf{r}' \Delta_s^*(\mathbf{r}, \mathbf{r}') u_i(\mathbf{r}') = E_i v_i(\mathbf{r})$$

$$v_{s}[\rho,\chi](\mathbf{r}) = v_{ext} + v_{H}^{ee}[\rho] + v_{xc}[\rho,\chi]$$
$$= \int d\mathbf{r} \cdot \frac{\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} + \frac{\delta F_{xc}}{\delta\rho(\mathbf{r})}$$
$$\Delta_{s}[\rho,\chi](\mathbf{r},\mathbf{r}') = \Delta_{ext} + \Delta_{H} + \Delta_{xc}$$
$$= -\frac{\chi(\mathbf{r},\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} + \frac{\delta F_{xc}}{\delta\chi^{*}(\mathbf{r},\mathbf{r}')}$$

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Gap equation

Oliveira et al., PRL 60, 2430 (1988)M. Lüders et al, PRB <u>72</u>, 024545 (2005)Kreibich & Gross PRL 86, 2984 (2001)M. Marques et al, PRB <u>72</u>, 024546 (2005)

Linearized gap equation

$$\Delta_{i} = \frac{-1}{2} \sum_{j} F_{ij}^{\text{Hxc}} \frac{\tanh[\beta \xi_{j} / 2]}{\xi_{j}} \Delta_{j}$$

$$F_{ij}^{\text{Hxc}} = \frac{\delta^2 (E_H + F_{xc})}{\delta \chi_i^* \delta \chi_j}$$

$$E_{H} = \frac{1}{2} \int d^{3}r \int d^{3}r \, \frac{\rho(\mathbf{r})\rho(\mathbf{r'})}{|\mathbf{r} - \mathbf{r'}|} + \int d^{3}r \int d^{3}r \, \frac{|\chi(\mathbf{r}, \mathbf{r'})|^{2}}{|\mathbf{r} - \mathbf{r'}|}$$

Once F_{xc} is given, we can calculate T_c without adjustable parameters

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Migdal-Eliashberg Theory

Self-consistent perturbation theory: lowest-order dressed-phonon and dressed Coulomb contribution to Σ retained

(Nambu-Gor'kov formalism)

$$\overline{\Sigma}(\mathbf{k}, i\omega_n) = -k_B T \sum_{\mathbf{k}', n'} \overline{\tau_3 G}(\mathbf{k}', i\omega_{n'}) \overline{\tau_3} \left[\sum_{\lambda} \left\{ g_{\mathbf{k}\mathbf{k}'\lambda} \right\}^2 D_{\lambda}(\mathbf{k} - \mathbf{k}', i\omega_n - i\omega_{n'}) + V_c(\mathbf{k} - \mathbf{k}') \right] \frac{d^4 p'}{(2\pi)^4}$$



Damping and retardation effects are considered

Can we take account of these effects in the framework of DFT ?

In DFT, everything is represented in terms of density ...



Retardation effect in SCDFT

Gap equation in SCDFT \rightarrow No ω dependence, but state dependent





Application to simple metals





Application to simple metals

M. Lüders et al, PRB <u>72</u>, 024545 (2005), M. Marques et al, PRB <u>72</u>, 024546 (2005)

Transition temperatures from DFT calculation

	Al	Nb	Ta	Pb	Cu
DFT	0.9	9.5	3.7	6.9	<0.01
Experimental	1.18	9.5	4.5	7.2	-

Gap at zero temperature

	Al	Nb	Ta	Pb	Cu
DFT	0.14	1.74	0.63	1.34	-
Experimental	0.179	1.55	0.69	1.33	-





Application to MgB₂





Application to unconventional SC



R. Akashi and RA, arXiv:1303.5152

MNX M=Zr, Hf X= CI, Br, I

R. Akashi, K. Nakamura, RA and M. Imada PRB2012



DFT for unconventional SC

It is an interesting challenge to formulate DFT for unconventional SC

- spin-fluctuation mediated SC
- orbital-fluctuation mediated SC
- exciton mechanism
- plasmon mechanism

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Plasmon mechanism

Proposed by Y. Takada JPSJ 45 786 (1978)



Fig. 2. Calculated results of T_c for several values of m^* , κ , and g_v . A 2D system is treated in (a), while a 3D one is in (b).

Superconducting ground state for large r_s



Plasmon mechanism



Fig. 6. Calculated T_c as a function of *n* for several values of m^* in the plasmon-FE soft phonon mechanism of superconductivity.

Cooperation of phonon & plasmon enhances pairing instability

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SC in doped insulators

Field-induced SC has been observed in a variety of band insulators



K. Ueno et al., Nature Nanotechnology 6 408 (2011) J.T. Ye et al., Science 338 1193 (2012)

Tc has a dope-like shape Peak in low density region

How to describe the plasmon mechanism in DFT

$$\Delta_{i} = \frac{-1}{2} \sum_{j} K_{ij}^{\text{Hxc}} \frac{\tanh[\beta \xi_{j}/2]}{\xi_{j}} \Delta_{j} \qquad K_{ij}^{\text{Hxc}} = \frac{\delta^{2}(E_{H} + F_{xc})}{\delta \chi_{i}^{*} \delta \chi_{j}}$$

Kohn-Sham perturbation theory (F, D, V_c are obtained from first-principles calc.)



F (anomalous Green fn.)



Static screened Coulomb V_c

How to describe the plasmon mechanism in DFT

$$\Delta_{i} = \frac{-1}{2} \sum_{j} K_{ij}^{\text{Hxc}} \frac{\tanh[\beta \xi_{j}/2]}{\xi_{j}} \Delta_{j} \qquad K_{ij}^{\text{Hxc}} = \frac{\delta^{2}(E_{H} + F_{xc})}{\delta \chi_{i}^{*} \delta \chi_{j}}$$

Kohn-Sham perturbation theory (F, D, V_c are obtained from first-principles calc.)



F (anomalous Green fn.)



Dynamical screened Coulomb $V_c(\omega)$ with plasmon-pole approximation

How to describe the plasmon mechanism in DFT

Kohn-Sham perturbation theory (F, D, V_c are obtained from first-principles calc.)



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Li: band structure



Band structure ~ Nearly Free Electron (NFE) model

High T_c SC in Li under high pressure: experiments



Shimizu et al., Nature 419, 597 (2002) $T_c{\sim}20K$ at 48GPa



Struzhkin et al., Science 298, 1213 (2002)



Deemyad and Schilling, PRL 91, 167001 (2003)

Li under high pressure: conventional scenario?



Pressure [GPa]	14	20	30
Ele-ph coupling (λ)	0.522	0.623	0.812

Consistent with T. Bazirov et al., PRB 82, 184509 (2010)

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Conventional SCDFT calc. for Li



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High T_c SC in Li under high pressure: experiments



Shimizu et al., Nature 419, 597 (2002) $T_c \sim 20K$ at 48GPa (highest T_c of any elements)



Struzhkin et al., Science 298, 1213 (2002)



Deemyad and Schilling, PRL 91, 167001 (2003)



Application to Li: Exch-Corr. Kernel







Application to Li: Exch-Corr. Kernel









Application to Li: Exch-Corr. Kernel









Application to Li: Gap function at T=0



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Application to Li: Gap function





Application to Li: T_c





Application to AI: T_c





Summary & Outlook

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Development of SCDFT for unconventional SC

- Plasmon assisted SC
- Application to Li under high pressure

- Application to other systems such as MoS₂, HfNCI, ...
- Development of SCDFT for other mechanisms
 - Spin fluctuation mediated SC

